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## November 2013

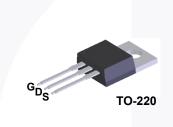
## FQP65N06 N-Channel QFET<sup>®</sup> MOSFET 60 V, 65 A, 16 mΩ

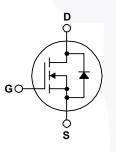
## Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

### Features

- 65 A, 60 V,  $R_{DS(on)}$  = 16 m $\Omega$  (Max.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 32.5 A
- Low Gate Charge (Typ. 48 nC)
- Low Crss (Typ. 100 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





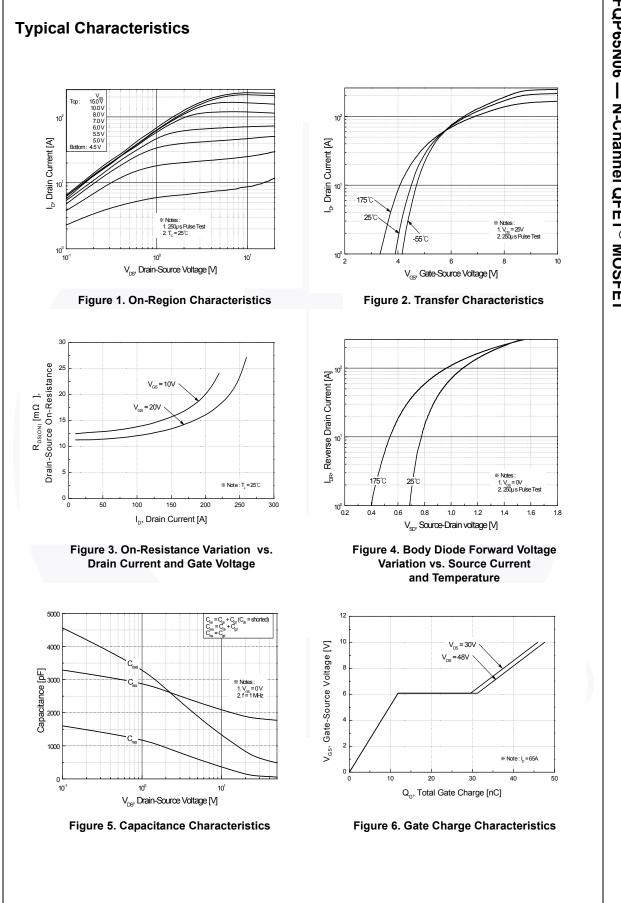
## Absolute Maximum Ratings T<sub>c</sub> = 25°C unless otherwise noted.

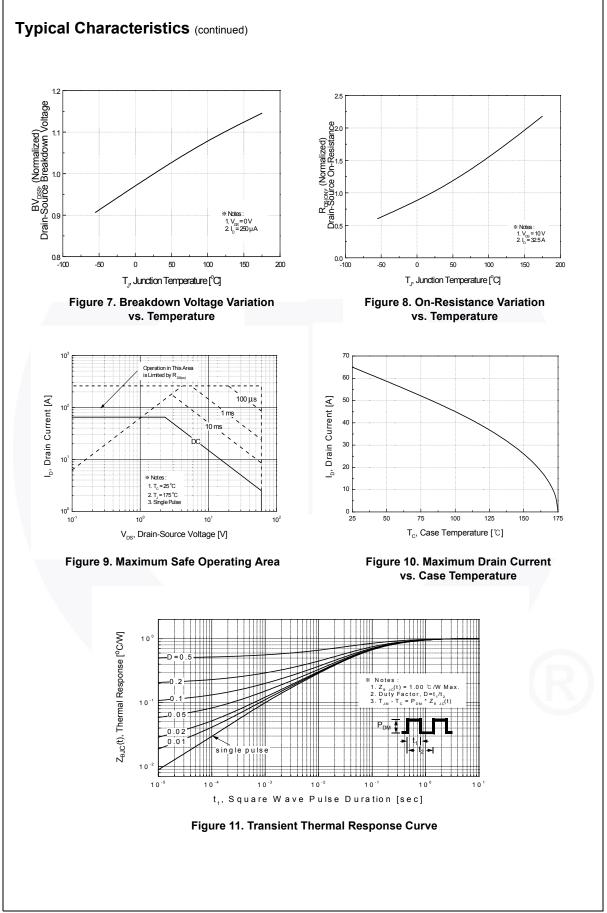
Symbol	Parameter		FQP65N06	Unit
V <sub>DSS</sub>	Drain-Source Voltage		60	V
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°	C)	65	A
	- Continuous (T <sub>C</sub> = 100	)°C)	46.1	A
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	260	A
V <sub>GSS</sub>	Gate-Source Voltage		± 25	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy	(Note 2)	650	mJ
I <sub>AR</sub>	Avalanche Current	(Note 1) 65		A
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	15.0	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	7.0	V/ns
PD	Power Dissipation (T <sub>C</sub> = 25°C)		150	W
	- Derate above 25°C		1.00	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +175	°C
ΤL	Maximum Lead Temperature for Solderir 1/8" from Case for 5 seconds	ng,	300	°C

## **Thermal Characteristics**

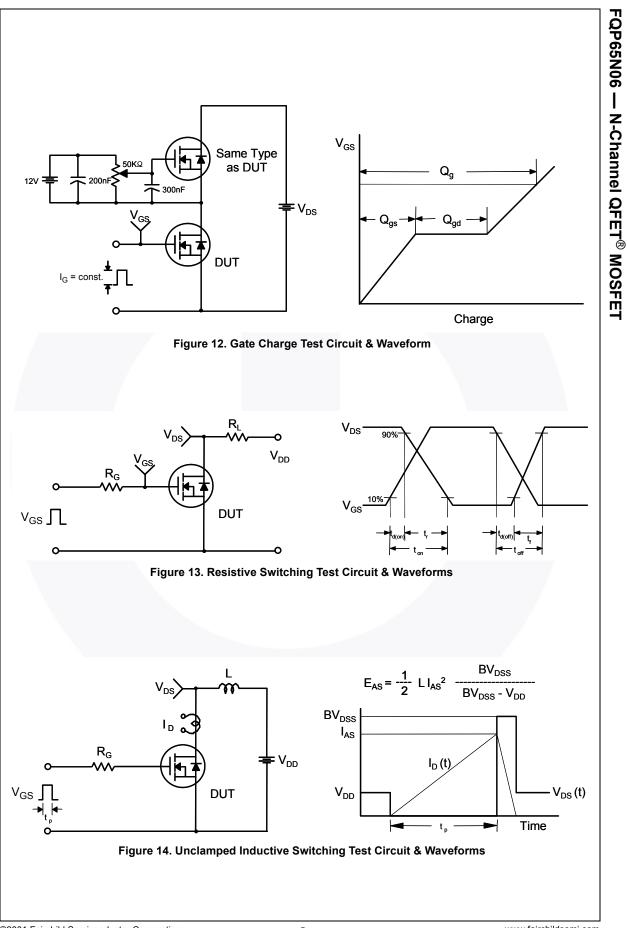
Symbol	Parameter	FQP65N06	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	1.00	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

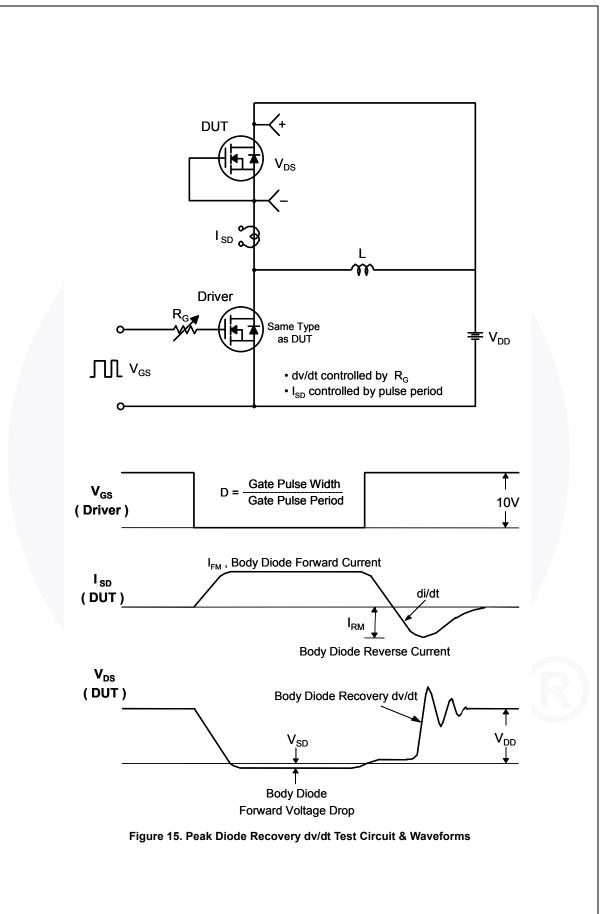
Part NumberTop MarkPackageFQP65N06FQP65N06TO-220		Package	e Packing Method Re		Size	Tape Width		h Q	Quantity	
		Tube N/A		/A	N/A		5	50 units		
lectri	cal C	naracteristics	T <sub>C</sub> = 25°C	unless otherwise noted.						
Symbol		Parameter		Test Cond	itions		Min	Тур	Max	Unit
Off Cha	aracte	istics								
V <sub>DSS</sub>	1	Source Breakdown V	oltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250	) uA		60			V
BV <sub>DSS</sub> ΔT <sub>J</sub>		down Voltage Temper	U	$I_D = 250 \ \mu\text{A}, \text{Reference}$		25°C		0.07		V/°C
DSS				V <sub>DS</sub> = 60 V, V <sub>GS</sub> =	0 V				1	μA
	Zero G	Sate Voltage Drain Cu	urrent	$V_{DS} = 48 \text{ V}, \text{ T}_{C} = 18$	50°C				10	μA
GSSF	Gate-E	Body Leakage Currer	t, Forward	V <sub>GS</sub> = 25 V, V <sub>DS</sub> =	0 V	1			100	nA
SSSR		Body Leakage Currer		$V_{GS}$ = -25 V, $V_{DS}$ =					-100	nA
On Cha	aracter	istics								
GS(th)	Gate 1	hreshold Voltage		$V_{DS} = V_{GS}, I_D = 25$	0 μΑ		2.0		4.0	V
RDS(on)		Drain-Source sistance		$V_{GS}$ = 10 V, I <sub>D</sub> = 32.5	5A			0.012	0.016	Ω
FS	Forwa	rd Transconductance		V <sub>DS</sub> = 25 V, I <sub>D</sub> = 32	2.5 A			48		S
viss voss	Input (	racteristics Capacitance t Capacitance		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 1 f = 1.0 MHz	0 V,			1850 700	2410 910	pF pF
rss		se Transfer Capacita	nce	1 1.0 10112				100	130	pF
Switch	· · ·	aracteristics							1	
l(on)		n Delay Time		V <sub>DD</sub> = 30 V, I <sub>D</sub> = 32	2.5 A,			20	50	ns
		In Rise Time		R <sub>G</sub> = 25 Ω				160	330	ns
l(off)	Turn-C	off Delay Time						90	190	ns
	Turn-C	off Fall Time			(N	lote 4)		105	220	ns
) <sup>g</sup>	Total C	Bate Charge		V <sub>DS</sub> = 48 V, I <sub>D</sub> = 65	5 A,			48	65	nC
) <sub>gs</sub>	Gate-S	Source Charge		V <sub>GS</sub> = 10 V				12		nC
l <sub>gd</sub>	Gate-I	Drain Charge			(N	lote 4)		19.5		nC
)rain-S	Source	Diode Characte	eristics an	d Maximum Ra	tinas					
3		um Continuous Drair			U				65	А
SM	Maxim	um Pulsed Drain-So	urce Diode Fo	orward Current					260	А
SD		Source Diode Forwar	1	$V_{GS} = 0 V, I_{S} = 65 A$	A				1.5	V
r		se Recovery Time		$V_{GS} = 0 V, I_S = 65 A,$				62		ns
l Prr		se Recovery Charge		$dI_{\rm F} / dt = 100  {\rm A}/{\mu s}$				110		nC
		in the second seco								

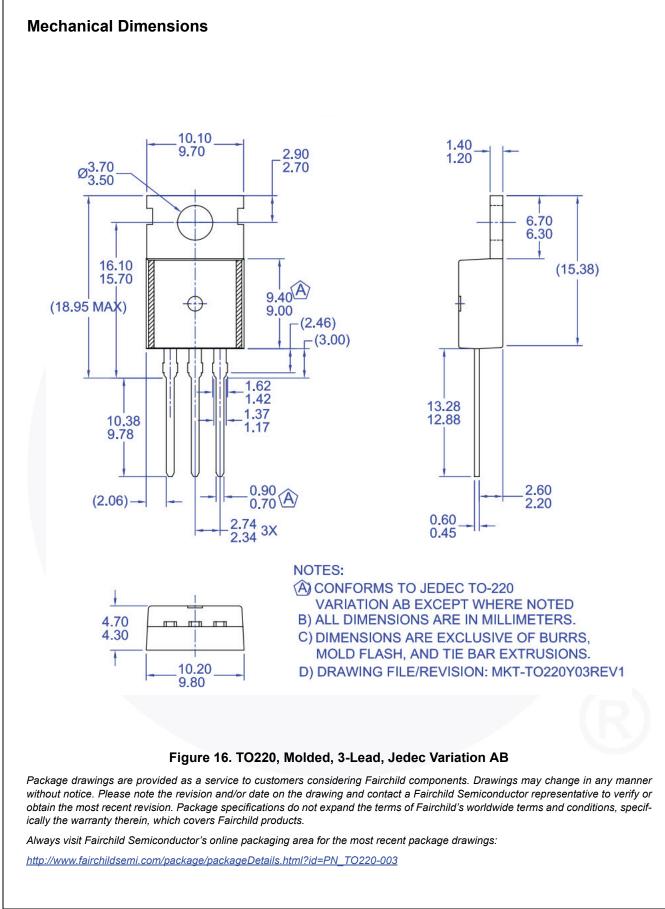




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